

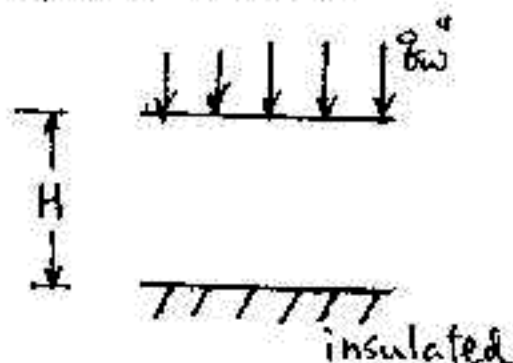
八十八學年度 工科系 系(所) 乙 組碩士班研究生招生考試

科目 熱傳學 科號 3304 共 2 頁第 1 頁 *請在試卷【答案卷】內作答

1. 請用公式定義以下名詞，並描述物理意義 (25 分)

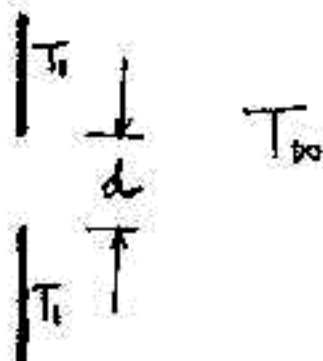
- (a) Blackbody
- (b) Nusselt number
- (c) Reynolds number
- (d) Prandtl number
- (e) Raleigh number

2. 平行水平板間層流流場若為 Thermally & hydraulically fully developed 一面板 $q_w = \text{const}$ ，一面板絕緣，求導兩片板各自之 Nusselt number

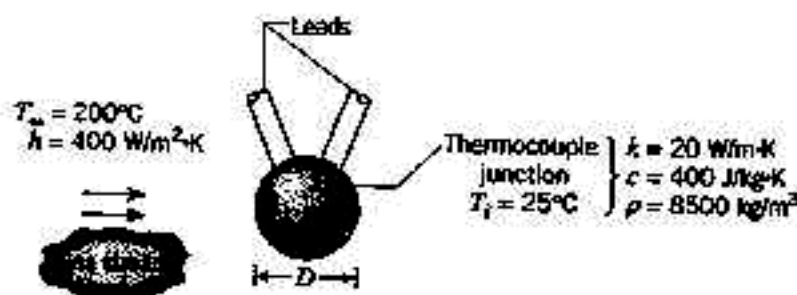


(30 分)

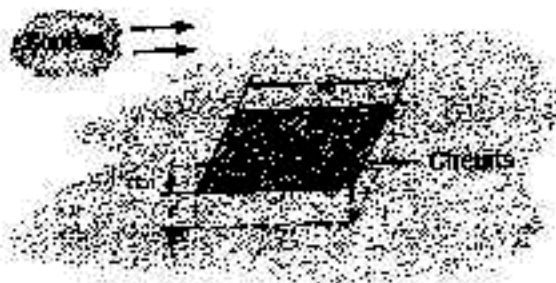
3. 兩塊平板 (如圖) 之間的距離為 d ，兩板的溫度皆為 T_1 ，放在室溫為 T_∞ ($T_1 > T_\infty$) 的環境中，請問距離 d 對熱傳的影響，為什麼？ (20 分)



4. A thermocouple junction, which may be approximated as a sphere, is to be used for temperature measurement in a gas stream. The convection coefficient between the junction surface and the gas is known to be $h = 400 \text{ W/in}^2 \cdot \text{K}$, and the junction thermophysical properties are $k = 20 \text{ W/in} \cdot \text{K}$, $c = 400 \text{ J/kg} \cdot \text{K}$, and $\rho = 8500 \text{ kg/m}^3$. Determine the junction diameter needed for the thermocouple to have a time constant of 1 s. If the junction is at 25°C and is placed in a gas stream that is at 200°C , how long will it take for the junction to reach 199°C ? (15 分)



5. A square silicon chip ($k = 150 \text{ W/in} \cdot \text{K}$) is of width $w = 5 \text{ mm}$ on a side and of thickness $t = 1 \text{ mm}$. The chip is mounted in a substrate such that its side and back surfaces are insulated, while the front surface is exposed to a coolant.



If 4 W are being dissipated in circuits mounted to the back surface of the chip, what is the steady-state temperature difference between back and front surface? (10 分)